

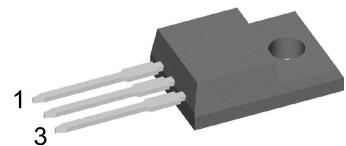
Thyristor

V_{RRM} = 1600 V
 I_{TAV} = 23 A
 V_T = 1.42 V

Single Thyristor

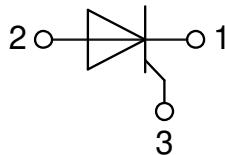
Part number

CMA30E1600PN



Backside: Isolated

 E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-220FP

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

Disclaimer Notice

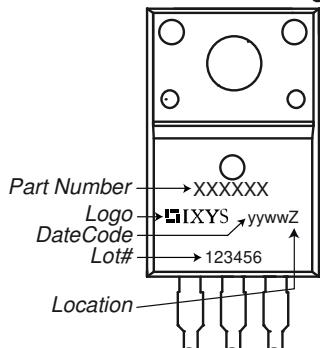
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Thyristor

| Symbol | Definition | Conditions | Ratings | | | |
|----------------|--|--|---|------|---------|------------------------|
| | | | min. | typ. | max. | |
| $V_{RSM/DSM}$ | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^\circ\text{C}$ | | | 1700 | V |
| $V_{RRM/DRM}$ | max. repetitive reverse/forward blocking voltage | $T_{VJ} = 25^\circ\text{C}$ | | | 1600 | V |
| $I_{R/D}$ | reverse current, drain current | $V_{R/D} = 1600 \text{ V}$ $V_{R/D} = 1600 \text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$ | | 10 2 | μA mA |
| V_T | forward voltage drop | $I_T = 30 \text{ A}$ | $T_{VJ} = 25^\circ\text{C}$ | | 1.42 | V |
| | | $I_T = 60 \text{ A}$ | | | 1.80 | V |
| | | $I_T = 30 \text{ A}$ | $T_{VJ} = 125^\circ\text{C}$ | | 1.42 | V |
| | | $I_T = 60 \text{ A}$ | | | 1.92 | V |
| I_{TAV} | average forward current | $T_C = 40^\circ\text{C}$ | $T_{VJ} = 150^\circ\text{C}$ | | 23 | A |
| $I_{T(RMS)}$ | RMS forward current | 180° sine | | | 36 | A |
| V_{T0} | threshold voltage | $\left. \begin{array}{l} \text{slope resistance} \\ \end{array} \right\} \text{for power loss calculation only}$ | $T_{VJ} = 150^\circ\text{C}$ | | 0.90 | V |
| r_T | slope resistance | | | | 17 | $\text{m}\Omega$ |
| R_{thJC} | thermal resistance junction to case | | | | 2.5 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0.5 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^\circ\text{C}$ | | 50 | W |
| I_{TSM} | max. forward surge current | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ\text{C}$ | | 260 | A |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 280 | A |
| | | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 150^\circ\text{C}$ | | 220 | A |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 240 | A |
| I^2t | value for fusing | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ\text{C}$ | | 340 | A^2s |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 325 | A^2s |
| | | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 150^\circ\text{C}$ | | 240 | A^2s |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 240 | A^2s |
| C_J | junction capacitance | $V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$ | $T_{VJ} = 25^\circ\text{C}$ | 9 | | pF |
| P_{GM} | max. gate power dissipation | $t_p = 30 \mu\text{s}$ | $T_C = 150^\circ\text{C}$ | | 10 | W |
| | | $t_p = 300 \mu\text{s}$ | | | 5 | W |
| P_{GAV} | average gate power dissipation | | | | 0.5 | W |
| $(di/dt)_{cr}$ | critical rate of rise of current | $T_{VJ} = 125^\circ\text{C}; f = 50 \text{ Hz}$ repetitive, $I_T = 90 \text{ A}$ | | | 150 | $\text{A}/\mu\text{s}$ |
| | | $t_p = 200 \mu\text{s}; di_G/dt = 0.2 \text{ A}/\mu\text{s};$ | | | | |
| | | $I_G = 0.2 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 30 \text{ A}$ | | | 500 | $\text{A}/\mu\text{s}$ |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage | $V = \frac{2}{3} V_{DRM}$ | $T_{VJ} = 125^\circ\text{C}$ | | 500 | $\text{V}/\mu\text{s}$ |
| | | $R_{GK} = \infty$; method 1 (linear voltage rise) | | | | |
| V_{GT} | gate trigger voltage | $V_D = 6 \text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ | | 1.3 | V |
| | | | $T_{VJ} = -40^\circ\text{C}$ | | 1.6 | V |
| I_{GT} | gate trigger current | $V_D = 6 \text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ | | 28 | mA |
| | | | $T_{VJ} = -40^\circ\text{C}$ | | 50 | mA |
| V_{GD} | gate non-trigger voltage | $V_D = \frac{2}{3} V_{DRM}$ | $T_{VJ} = 125^\circ\text{C}$ | | 0.2 | V |
| I_{GD} | gate non-trigger current | | | | 1 | mA |
| I_L | latching current | $t_p = 10 \mu\text{s}$ | $T_{VJ} = 25^\circ\text{C}$ | | 90 | mA |
| | | $I_G = 0.2 \text{ A}; di_G/dt = 0.2 \text{ A}/\mu\text{s}$ | | | | |
| I_H | holding current | $V_D = 6 \text{ V}$ $R_{GK} = \infty$ | $T_{VJ} = 25^\circ\text{C}$ | | 80 | mA |
| t_{gd} | gate controlled delay time | $V_D = \frac{1}{2} V_{DRM}$ | $T_{VJ} = 25^\circ\text{C}$ | | 2 | μs |
| | | $I_G = 0.5 \text{ A}; di_G/dt = 0.5 \text{ A}/\mu\text{s}$ | | | | |
| t_q | turn-off time | $V_R = 100 \text{ V}; I_T = 30 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ\text{C}$ | $di/dt = 10 \text{ A}/\mu\text{s}$ $dv/dt = 20 \text{ V}/\mu\text{s}$ $t_p = 200 \mu\text{s}$ | 150 | | μs |

Package TO-220FP

| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
|---------------|--|---|--------------|------|------|--------|
| I_{RMS} | RMS current | per terminal | | | 35 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 150 | °C |
| Weight | | | | 2 | | g |
| M_d | mounting torque | | 0.4 | | 0.6 | Nm |
| F_c | mounting force with clip | | 20 | | 60 | N |
| $d_{Spp/App}$ | creepage distance on surface / striking distance through air | terminal to terminal | 1.6 | 1.0 | | mm |
| $d_{Spb/Abp}$ | | terminal to backside | 2.5 | 2.5 | | mm |
| V_{ISOL} | isolation voltage | t = 1 second t = 1 minute 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 2500 2100 | | | V V |

Product Marking

Part description

C = Thyristor (SCR)
 M = Thyristor
 A = (up to 1800V)
 30 = Current Rating [A]
 E = Single Thyristor
 1600 = Reverse Voltage [V]
 PN = TO-220ABFP (3)

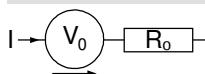
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | CMA30E1600PN | CMA30E1600PN | Tube | 50 | 505254 |

| Similar Part | Package | Voltage class |
|--------------|------------------------|---------------|
| CMA30E1600PB | TO-220AB (3) | 1600 |
| CMA30E1600PZ | TO-263AB (D2Pak) (2HV) | 1600 |
| CS22-12io1M | TO-220ABFP (3) | 1200 |
| CLA30E1200PB | TO-220AB (3) | 1200 |

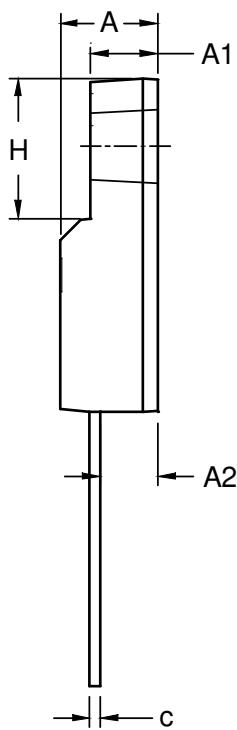
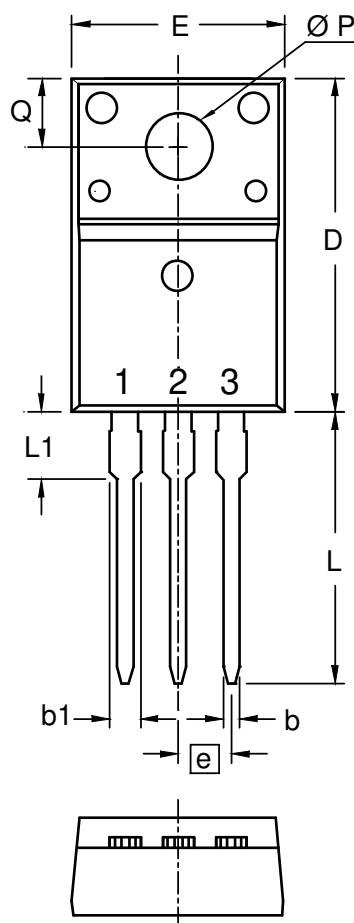
| | | |
|--------------|----------------------|------|
| CLA30E1200PC | TO-263AB (D2Pak) (2) | 1200 |
| CLA30E1200HB | TO-247AD (3) | 1200 |
| CS22-08io1M | TO-220ABFP (3) | 800 |

Equivalent Circuits for Simulation
^{*}on die level

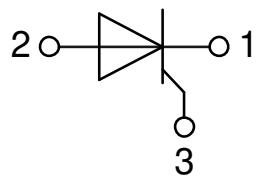
 $T_{VJ} = 150^\circ\text{C}$

| | |
|---|--------------------|
|  | Thyristor |
| $V_{0\max}$ | threshold voltage |
| $R_{0\max}$ | slope resistance * |

V
 $\text{m}\Omega$

Outlines TO-220FP


| Dim. | Millimeters | | Inches | |
|------|-------------|-------|-----------|-------|
| | min | max | min | max |
| A | 4.50 | 4.90 | 0.177 | 0.193 |
| A1 | 2.34 | 2.74 | 0.092 | 0.108 |
| A2 | 2.56 | 2.96 | 0.101 | 0.117 |
| b | 0.70 | 0.90 | 0.028 | 0.035 |
| c | 0.45 | 0.60 | 0.018 | 0.024 |
| D | 15.67 | 16.07 | 0.617 | 0.633 |
| E | 9.96 | 10.36 | 0.392 | 0.408 |
| e | 2.54 BSC | | 0.100 BSC | |
| H | 6.48 | 6.88 | 0.255 | 0.271 |
| L | 12.68 | 13.28 | 0.499 | 0.523 |
| L1 | 3.03 | 3.43 | 0.119 | 0.135 |
| ØP | 3.08 | 3.28 | 0.121 | 0.129 |
| Q | 3.20 | 3.40 | 0.126 | 0.134 |



Thyristor

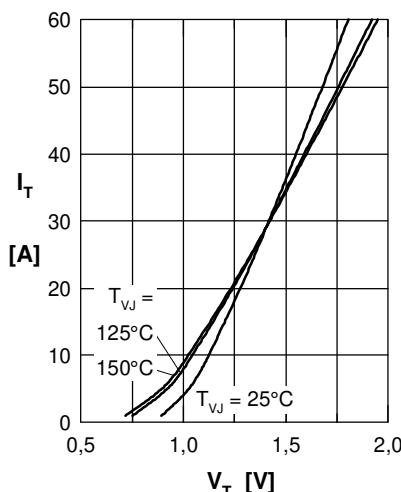


Fig. 1 Forward characteristics

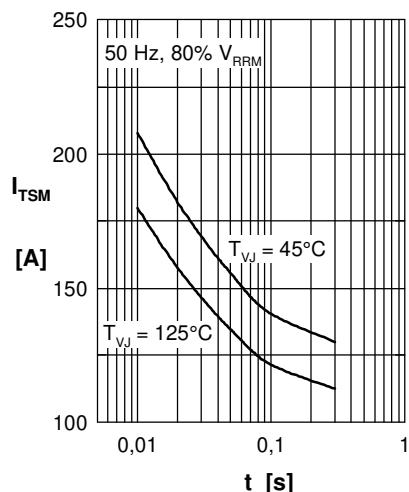


Fig. 2 Surge overload current
 I_{TSM} : crest value, t : duration

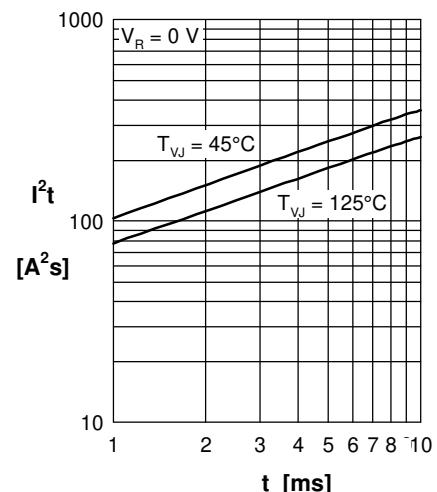


Fig. 3 I^2t versus time (1-10 s)

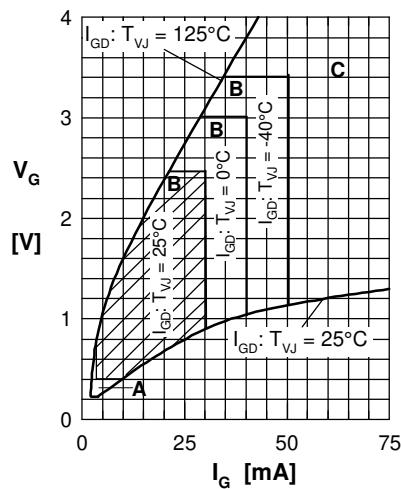


Fig. 4 Gate voltage & gate current
Triggering: A = no; B = possible; C = safe

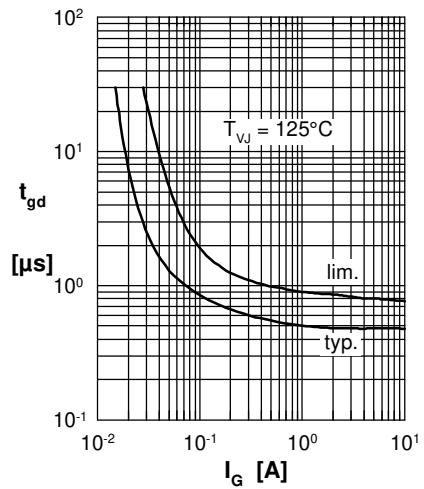


Fig. 5 Gate controlled delay time t_{gd}

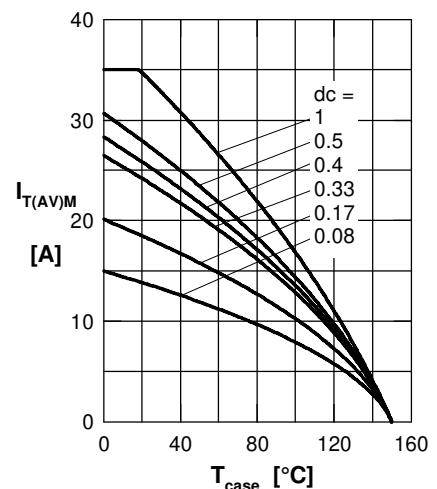


Fig. 6 Max. forward current at case temperature

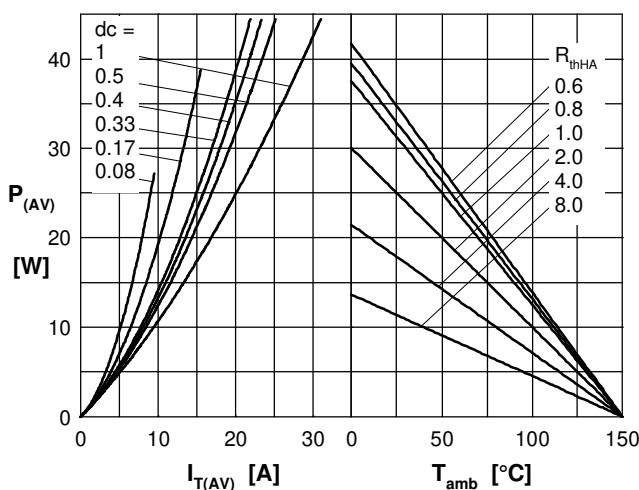


Fig. 7a Power dissipation versus direct output current
Fig. 7b and ambient temperature

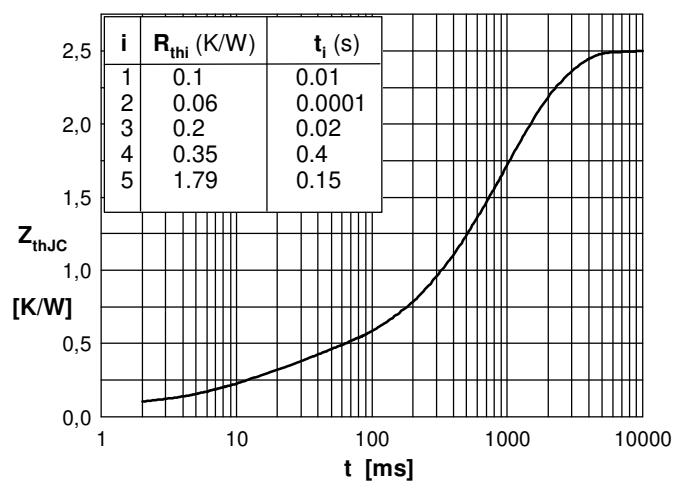


Fig. 7 Transient thermal impedance junction to case

